BATTERY PROTECTION IC (FOR A 2-SERIAL-CELL PACK)   S-8232 Series

The 8232 is a series of lithium-ion rechargeable battery protection ICs incorporating high-accuracy voltage detection circuits and delay circuits.
The S-8232 is suitable for a 2-serial-cell lithium-ion battery pack.

■ Features

(1)   Internal high-accuracy voltage detection circuit
   • Overcharge detection voltage   3.90 V ± 25 mV to 4.60 V ± 25 mV
                                                      5 mV- step
   • Overcharge release voltage   3.60 V ± 50 mV to 4.60 V ± 50 mV
                                                      5 mV- step

   (The Overcharge release voltage can be selected within the range where a difference from
   Overcharge detection voltage is 0 to 0.3 V)

   • Overdischarge detection voltage   1.70 V ± 80 mV to 2.60 V ± 80 mV
                                                      50 mV- step
   • Overdischarge release voltage   1.70 V ± 100 mV to 3.80 V ± 100 mV
                                                      50 mV - step

   (The Overdischarge release voltage can be selected within the range where a difference from
   Overdischarge detection voltage is 0 to 1.2 V)

   • Overcurrent detection voltage 1   0.07 V ± 20 mV to 0.30 V ± 20 mV
                                                      5 mV-step

(2)   High input-voltage device (absolute maximum rating: 18 V)
(3)   Wide operating voltage range: 2.0 V to 16 V
(4)   The delay time for every detection can be set via an external capacitor.
       Each delay time for Overcharge detection, Overdischarge detection, Overcurrent detection are
       "Proportion of hundred to ten to one."
(5)   Two overcurrent detection levels (protection for short-circuiting)
(6)   Internal auxiliary over voltage detection circuit (Fail safe for over voltage)
(7)   Internal charge circuit for 0 V battery (Unavailable is option)
(8)   Low current consumption
   • Operation   7.5 µA typ. 14.2 µA max (−40 to +85 °C)
   • Power-down mode   0.2 nA typ.   0.1 µA max (−40 to +85 °C)
(9)   TSSOP package (8-pin) 6.4 mm×3.1 mm

■ Applications

Lithium-ion rechargeable battery packs

■ Package

8-PinTSSOP (PKG code:FT008-A)

■ Selection Guide (01 .Nov ,2001)

Table1

Model/Item	Overcharge detection voltage1,2 ($V_{CU1,2}$)	Overcharge release voltage1,2 ($V_{CD1,2}$)	Overdischarge detection voltage1,2 ($V_{DD1,2}$)	Overdischarge release voltage1,2 ($V_{DU1,2}$)	Overcurrent detection voltage1 (V_{IOV1})	Overcharge detection delay time (t_{CU}) C3=0.22 μF	0 V battery charging function
S-8232AAFT	4.25V±25mV	4.05±50mV	2.40V±80mV	3.00V±100mV	0.150V±20mV	1.0 s	Available
S-8232ABFT	4.35V±25mV	4.15±50mV	2.30V±80mV	3.00V±100mV	0.300V±20mV	1.0 s	Available
S-8232ACFT	4.35V±25mV	4.15±50mV	2.30V±80mV	3.00V±100mV	0.300V±20mV	1.0 s	Unavailable
S-8232AEFT	4.35V±25mV	4.28±50mV	2.15V±80mV	2.80V±100mV	0.100V±20mV	1.0 s	Available
S-8232AFFT	4.25V±25mV	4.05±50mV	2.30V±80mV	2.70V±100mV	0.300V±20mV	1.0 s	Available
S-8232AGFT	4.25V±25mV	4.05±50mV	2.20V±80mV	2.40V±100mV	0.200V±20mV	1.0 s	Available
S-8232AHFT	4.25V±25mV	4.05±50mV	2.20V±80mV	2.40V±100mV	0.300V±20mV	1.0 s	Available
S-8232AIFT	4.325V±25mV	4.325V±25mV [1),2)]	2.40V±80mV	3.00V±100mV	0.300V±20mV	1.0 s	Unavailable
S-8232AJFT	4.25V±25mV	4.05±50mV	2.40V±80mV	3.00V±100mV	0.150V±20mV	1.0 s	Unavailable
S-8232AKFT	4.20V±25mV	4.00±50mV	2.30V±80mV	2.90V±100mV	0.200V±20mV	1.0 s	Available
S-8232ALFT	4.30V±25mV	4.05±50mV	2.00V±80mV	3.00V±100mV	0.200V±20mV	1.0 s	Available
S-8232AMFT	4.19V±25mV	4.19 V±25mV [1)]	2.00V±80mV	3.00V±100mV	0.190V±20mV	1.0 s	Available
S-8232ANFT	4.325V±25mV	4.325V±25mV [1),3)]	2.40V±80mV	3.00V±100mV	0.300V±20mV	1.0 s	Unavailable
S-8232AOFT	4.30V±25mV	4.05±50mV	2.00V±80mV	3.00V±100mV	0.230V±20mV	1.0 s	Available
S-8232APFT	4.28V±25mV	4.05±50mV	2.30V±80mV	2.90V±100mV	0.100V±20mV	1.0 s	Unavailable
S-8232ARFT	4.325V±25mV	4.325V±25mV [1),3)]	2.00V±80mV	2.50V±100mV	0.300V±20mV	1.0 s	Unavailable
S-8232ASFT [4)]	4.295V±25mV	4.20±50mV [3)]	2.30V±80mV	3.00V±100mV	0.300V±20mV	1.0 s	Unavailable
S-8232ATFT	4.125V±25mV	4.125±25mV [1)]	2.00V±80mV	3.00V±100mV	0.190V±20mV	1.0 s	Available
S-8232AUFT	4.30V±25mV	4.10±50mV	2.40V±80mV	3.00V±100mV	0.200V±20mV	1.0 s	Unavailable
S-8232AVFT	4.30V±25mV	4.05±50mV	2.00V±80mV	3.00V±100mV	0.300V±20mV	1.0 s	Available
S-8232AWFT	4.35V±25mV	4.15±50mV	2.30V±80mV	3.00V±100mV	0.150V±20mV	1.0 s	Unavailable
S-8232AXFT	4.325V±25mV	4.200V±50mV	2.30V±80mV	3.00V±100mV	0.20V±20mV	1.0 s	Unavailable
S-8232AYFT	4.30V±25mV	4.05±50mV	2.00V±80mV	2.00V±80mV	0.20V±20mV	1.0 s	Available
S-8232AZFT	4.30V±25mV	4.05±50mV	2.30V±80mV	2.30V±80mV	0.20V±20mV	1.0 s	Available
S-8232NAFT	4.325V±25mV	4.325V±25mV [1), 3)]	2.40V±80mV	3.00V±100mV	0.15V±20mV	1.0 s	Unavailable
S-8232NCFT	4.275 V±25 mV	4.05 V±50 mV	2.20 V±80 mV	3.00 V±100 mV	0.20 V±20 mV	1.0 s	Unavailable
S-8232NDFT	4.35 V±25 mV	4.15 V±50 mV	2.30 V±80 mV	2.30 V±80 mV	0.15 V±20 mV	1.0 s	Available

1): No overcharge detection/release hysteresis
2): The magnification of final overcharge is 1.11; other is 1.25.
3): No final overcharging function
4): Refer to the Description of Operation (*3).

Change in the detection voltage is available. Please contact SII sales office.

The overdischarge detection voltage can be selected within the range from 1.7 to 3.0 V.
When the overdischarge detection voltage is higher than 2.6 V, the overcharge detection voltage and the overcharge release voltage are limited as table 2.

Table 2

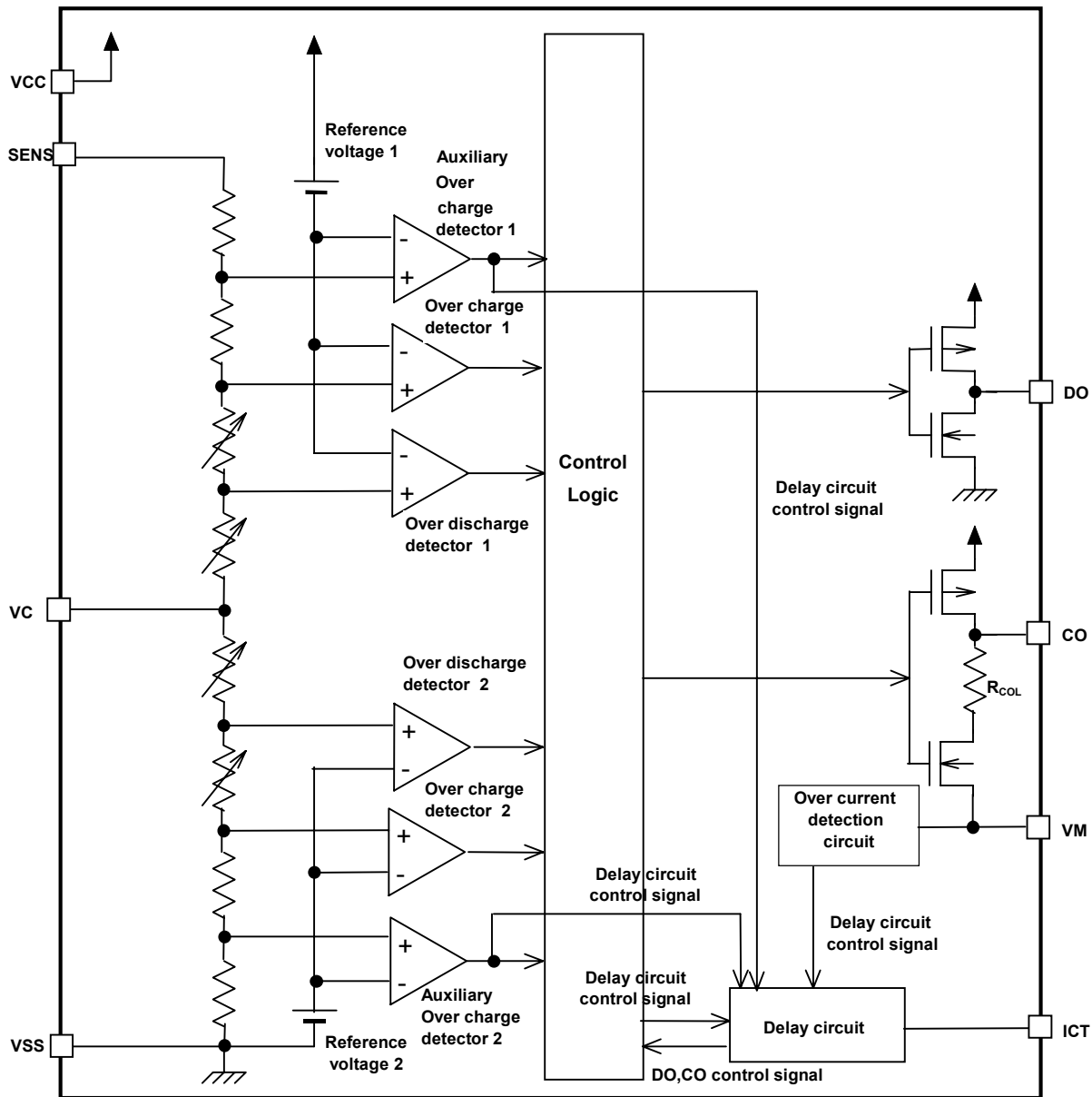| Overdischarge detection voltage1,2 ($V_{DD1,2}$)	Overcharge detection voltage1,2 ($V_{CU1,2}$)	Voltage difference between overcharge detection voltage and overcharge release voltage ($V_{CU1,2}$ - $V_{CD1,2}$)
1.70 to 2.60 V	3.90 to 4.60 V	0 to 0.30 V
1.70 to 2.80 V	3.90 to 4.60 V	0 to 0.20 V
1.70 to 3.00 V	3.90 to 4.50 V	0 to 0.10 V

■ Block Diagram

Figure 1

Output impedance when CO terminal output 'L' is higher than DO terminal. R_{COL} resistor is connected with CO terminal. Please refer 'Electric Characteristics'.

■ Pin Assignment

Top View

TSSOP-8
Figure 2
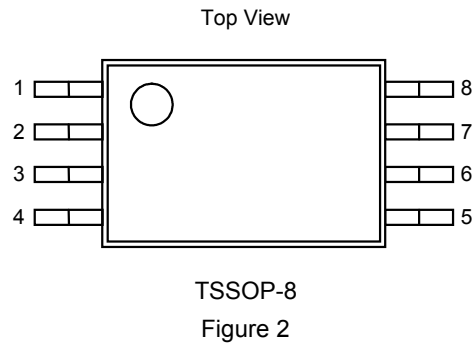
■ Pin Description

Table 3

No.	Name	Description
1	SENS	Detection pin for voltage between SENS and VC (Detection for overcharge and overdischarge)
2	DO	FET gate connection pin for discharge control (CMOS output)
3	CO	FET gate connection pin for charge control (CMOS output)
4	VM	Detection pin for voltage between VM and VSS (Overcurrent detection pin)
5	VSS	Negative power input pin
6	ICT	Capacitor connection pin for detection delay
7	VC	Middle voltage input pin
8	VCC	Positive power input pin

■ Absolute Maximum Ratings

Table 4   Ta = 25°C

Item	Symbol	Applied Pins	Rating	Unit
Input voltage between VCC and VSS	V_{DS}	VCC	$V_{SS}-0.3$ to $V_{SS}+18$	V
SENS Input terminal voltage	V_{SENS}	SENS	$V_{SS}-0.3$ to $V_{CC}+0.3$	V
ICT Input terminal voltage	V_{ICT}	ICT	$V_{SS}-0.3$ to $V_{CC}+0.3$	V
VM Input terminal voltage	V_{VM}	VM	$V_{CC}-18$ to $V_{CC}+0.3$	V
DO output terminal voltage	V_{DO}	DO	$V_{SS}-0.3$ to $V_{CC}+0.3$	V
CO output terminal voltage	V_{CO}	CO	$V_{VM}-0.3$ to $V_{CC}+0.3$	V
Power dissipation	P_D		300	mW
Operating temperature range	T_{opr}		-40 to $+85$	°C
Storage temperature range	T_{stg}		-40 to $+125$	°C

■ Electrical Characteristics

<div style="text-align:center">Table 5</div>
<div style="text-align:right">Unless otherwise noted, Ta = 25°C</div>

Item	Symbol	Condition	Circuit	Notice	Min.	Typ.	Max.	Unit
Detection voltage								
Overcharge detection voltage 1,2	$V_{CU1,2}$	1,2	1	Between 3.90 and 4.60	$V_{CU1,2}$ −0.025	$V_{CU1,2}$	$V_{CU1,2}$ +0.025	V
Auxiliary overcharge detection voltage 1,2 [4] $V_{CUaux}1,2 = V_{CU1,2} \times 1.25$	$V_{CUaux1,2}$	1,2	1	$V_{CU1,2} \times 1.25$	$V_{CU1,2}$ ×1.21	$V_{CU1,2}$ ×1.25	$V_{CU1,2}$ ×1.29	V
or $V_{CUaux}1,2 = V_{CU1,2} \times 1.11$	$V_{CUaux1,2}$	1,2	1	$V_{CU1,2} \times 1.11$	$V_{CU1,2}$ ×1.07	$V_{CU1,2}$ ×1.11	$V_{CU1,2}$ ×1.15	V
Overcharge release voltage 1,2	$V_{CD1,2}$	1,2	1	Between 3.60 and 4.60	$V_{CD1,2}$ −0.050	$V_{CD1,2}$	$V_{CD1,2}$ +0.050	V
Overdischarge detection voltage 1,2	$V_{DD1,2}$	1,2	1	Between 1.70 and 2.60	$V_{DD1,2}$ −0.080	$V_{DD1,2}$	$V_{DD1,2}$ +0.080	V
Overdischarge release voltage 1,2	$V_{DU1,2}$	1,2	1	Between 1.70 and 3.80	$V_{DU1,2}$ −0.100	$V_{DU1,2}$	$V_{DU1,2}$ +0.100	V
Overcurrent detection voltage 1	V_{IOV1}	3	1	Between 0.07 to 0.30	V_{IOV1}−0.020	V_{IOV1}	V_{IOV1}+0.020	V
Overcurrent detection voltage 2	V_{IOV2}	3	1	V_{CC} Reference	−1.57	−1.20	−0.83	V
Temperature coefficient 1 for detection voltage [1]	T_{COE1}			Ta=−40 to 85°C	−0.6	0	0.6	mV/°C
Temperature coefficient 2 for detection voltage [2]	T_{COE2}			Ta=−40 to 85°C	−0.24	−0.05	0	mV/°C
Delay time (C3=0.22 µF)								
Overcharge detection delay time1,2	$t_{CU1,2}$	8,9	5	1.0 s	0.73	1.00	1.35	s
Overdischarge detection delay time 1,2	$t_{DD1,2}$	8,9	5	0.1 s	68	100	138	ms
Overcurrent detection delay time1	t_{IOV1}	10	5	0.01 s	6.7	10	13.9	ms
Input voltage								
Input voltage between VCC and VSS	V_{DS}			Absolute maximum rating	−0.3	–	18	
Operating voltage								
Operating voltage between VCC and VSS [3]	V_{DSOP}				2.0	–	16	V
Current consumption								
Current consumption during normal operation	I_{OPE}	4	2	V1=V2=3.6 V	2.1	7.5	12.7	µA
Current consumption at power down	I_{PDN}	4	2	V1=V2=1.5 V	0	0.0002	0.04	µA
Output voltage								
DO"H"voltage	$V_{DO(H)}$	6	3	Iout=10 µA	V_{CC}−0.05	V_{CC}−0.003	V_{CC}	V
DO"L"voltage	$V_{DO(L)}$	6	3	Iout=10 µA	V_{SS}	V_{SS}+0.003	V_{SS}+0.05	V
CO"H"voltage	$V_{CO(H)}$	7	4	Iout=10 µA	V_{CC}−0.15	V_{CC}−0.019	V_{CC}	V
CO pin internal resistance								
Resistance between VSS and CO	R_{COL}	7	4	V_{CO}−V_{SS}=9.4 V	0.29	0.6	1.44	MΩ
Internal resistance								
Resistance between VCC and VM	R_{vcm}	5	2	Vcc−V_{VM}=0.5 V	105	240	575	kΩ
Resistance between VSS and VM	R_{vsm}	5	2	V_{VM}−V_{SS}=1.1 V	511	597	977	kΩ
0 V battery charging function								
0 V charge starting voltage	V_{0CHA}	11	6	0 V battery charging Available	0.38	0.75	1.12	V
0 V charge inhibiting voltage 1,2	$V_{0INH1,2}$	12,13	6	0 V battery charging Unavailable	0.32	0.88	1.44	V

(1) Temperature coefficient 1 for detection voltage should be applied to overcharge detection voltage, overcharge release voltage, overdischarge detection voltage, and overdischarge release voltage.

(2) Temperature coefficient 2 for detection voltage should be applied to overcurrent detection voltage.

(3) The DO and CO pin logic are established at the operating voltage.

(4) Auxiliary overcharge detection voltage is equal to the overcharge detection voltage times 1.11 for the products without overcharge hysteresis, and times 1.25 for other products.

Table 6 Unless otherwise noted, Ta $= -20$ to $+70°C$

Item	Symbol	Condition	Circuit	Notice	Min.	Typ.	Max.	Unit
Detection voltage								
Overcharge detection voltage 1,2	$V_{CU1,2}$	1,2	1	Between 3.90 and 4.60	$V_{CU1,2}$ -0.045	$V_{CU1,2}$	$V_{CU1,2}$ $+0.040$	V
Auxiliary overcharge detection voltage 1,2 [4] $V_{CUaux1,2} = V_{CU1,2} \times 1.25$ or $V_{CUaux1,2} = V_{CU1,2} \times 1.11$	$V_{CUaux1,2}$	1,2	1	$V_{CU1,2} \times 1.25$	$V_{CU1,2}$ $\times 1.19$	$V_{CU1,2}$ $\times 1.25$	$V_{CU1,2}$ $\times 1.31$	V
	$V_{CUaux1,2}$	1,2	1	$V_{CU1,2} \times 1.11$	$V_{CU1,2}$ $\times 1.05$	$V_{CU1,2}$ $\times 1.11$	$V_{CU1,2}$ $\times 1.17$	V
Overcharge release voltage 1,2	$V_{CD1,2}$	1,2	1	Between 3.60 and 4.60	$V_{CD1,2}$ -0.070	$V_{CD1,2}$	$V_{CD1,2}$ $+0.065$	V
Overdischarge detection voltage 1,2	$V_{DD1,2}$	1,2	1	Between 1.70 and 2.60	$V_{DD1,2}$ -0.100	$V_{DD1,2}$	$V_{DD1,2}$ $+0.095$	V
Overdischarge release voltage 1,2	$V_{DU1,2}$	1,2	1	Between 1.70 and 3.80	$V_{DU1,2}$ -0.120	$V_{DU1,2}$	$V_{DU1,2}$ $+0.115$	V
Overcurrent detection voltage 1	V_{IOV1}	3	1	Between 0.07 to 0.30	$V_{IOV1}-0.029$	V_{IOV1}	$V_{IOV1}+0.029$	V
Overcurrent detection voltage 2	V_{IOV2}	3	1	V_{CC} Reference	-1.66	-1.20	-0.74	V
Temperature coefficient 1 for detection voltage [1]	T_{COE1}			Ta=-40 to 85°C	-0.6	0	0.6	mV/°C
Temperature coefficient 2 for detection voltage [2]	T_{COE2}			Ta=-40 to 85°C	-0.24	-0.05	0	mV/°C
Delay time (C3=0.22 μF)								
Overcharge detection delay time1,2	$t_{CU1,2}$	8,9	5	1.0 s	0.60	1.00	1.84	s
Overdischarge detection delay time 1,2	$t_{DD1,2}$	8,9	5	0.1 s	67	100	141	ms
Overcurrent detection delay time1	t_{IOV1}	10	5	0.01 s	6.5	10	14.5	ms
Input voltage								
Input voltage between VCC and VSS	V_{DS}			Absolute maximum rating	-0.3	–	18	
Operating voltage								
Operating voltage between VCC and VSS [3]	V_{DSOP}				2.0	–	16	V
Current consumption								
Current consumption during normal operation	I_{OPE}	4	2	V1=V2=3.6 V	1.9	7.5	13.8	μA
Current consumption at power down	I_{PDN}	4	2	V1=V2=1.5 V	0	0.0002	0.06	μA
Output voltage								
DO"H"voltage	$V_{DO(H)}$	6	3	Iout=10 μA	$V_{CC}-0.14$	$V_{CC}-0.003$	V_{CC}	V
DO"L"voltage	$V_{DO(L)}$	6	3	Iout=10 μA	V_{SS}	$V_{SS}+0.003$	$V_{SS}+0.14$	V
CO"H"voltage	$V_{CO(H)}$	7	4	Iout=10 μA	$V_{CC}-0.24$	$V_{CC}-0.019$	V_{CC}	V
CO pin internal resistance								
Resistance between VSS and CO	R_{COL}	7	4	$V_{CO}-V_{SS}$=9.4 V	0.24	0.6	1.96	MΩ
Internal resistance								
Resistance between VCC and VM	R_{vcm}	5	2	$V_{CC}-V_{VM}$=0.5 V	86	240	785	kΩ
Resistance between VSS and VM	R_{vsm}	5	2	$V_{VM}-V_{SS}$=1.1 V	418	597	1332	kΩ
0 V battery charging function								
0 V charge starting voltage	V_{0CHA}	11	6	0 V battery charging Available	0.29	0.75	1.21	V
0 V charge inhibiting voltage 1,2	$V_{0INH1,2}$	12,13	6	0 V battery charging Unavailable	0.23	0.88	1.53	V

(1)   Temperature coefficient 1 for detection voltage should be applied to overcharge detection voltage, overcharge release voltage, overdischarge detection voltage, and overdischarge release voltage.

(2)   Temperature coefficient 2 for detection voltage should be applied to overcurrent detection voltage.

(3)   The DO and CO pin logic are established at the operating voltage.

(4)   Auxiliary overcharge detection voltage is equal to the overcharge detection voltage times 1.11 for the products without overcharge hysteresis, and times 1.25 for other products.

Table 7   Unless otherwise noted, Ta = −40 to +85°C

Item	Symbol	Condition	Circuit	Notice	Min.	Typ.	Max.	Unit
Detection voltage								
Overcharge detection voltage 1,2	$V_{CU1,2}$	1,2	1	Between 3.90 and 4.60	$V_{CU1,2}$ −0.055	$V_{CU1,2}$	$V_{CU1,2}$ +0.045	V
Auxiliary overcharge detection voltage 1,2 [4] $V_{CUaux1,2} = V_{CU1,2} \times 1.25$ or $V_{CUaux1,2} = V_{CU1,2} \times 1.11$	$V_{CUaux1,2}$	1,2	1	$V_{CU1,2} \times 1.25$	$V_{CU1,2}$ ×1.19	$V_{CU1,2}$ ×1.25	$V_{CU1,2}$ ×1.31	V
	$V_{CUaux1,2}$	1,2	1	$V_{CU1,2} \times 1.11$	$V_{CU1,2}$ ×1.05	$V_{CU1,2}$ ×1.11	$V_{CU1,2}$ ×1.17	V
Overcharge release voltage 1,2	$V_{CD1,2}$	1,2	1	Between 3.60 and 4.60	$V_{CD1,2}$ −0.080	$V_{CD1,2}$	$V_{CD1,2}$ +0.070	V
Overdischarge detection voltage 1,2	$V_{DD1,2}$	1,2	1	Between 1.70 and 2.60	$V_{DD1,2}$ −0.110	$V_{DD1,2}$	$V_{DD1,2}$ +0.100	V
Overdischarge release voltage 1,2	$V_{DU1,2}$	1,2	1	Between 1.70 and 3.80	$V_{DU1,2}$ −0.130	$V_{DU1,2}$	$V_{DU1,2}$ +0.120	V
Overcurrent detection voltage 1	V_{IOV1}	3	1	Between 0.07 to 0.30	V_{IOV1}−0.033	V_{IOV1}	V_{IOV1}+0.033	V
Overcurrent detection voltage 2	V_{IOV2}	3	1	V_{CC} Reference	−1.70	−1.20	−0.71	V
Temperature coefficient 1 for detection voltage [1]	T_{COE1}			Ta=−40 to 85°C	−0.6	0	0.6	mV/°C
Temperature coefficient 2 for detection voltage [2]	T_{COE2}			Ta=−40 to 85°C	−0.24	−0.05	0	mV/°C
Delay time (C3=0.22 μF)								
Overcharge detection delay time1,2	$t_{CU1,2}$	8,9	5	1.0 s	0.55	1.00	2.06	s
Overdischarge detection delay time 1,2	$t_{DD1,2}$	8,9	5	0.1 s	67	100	141	ms
Overcurrent detection delay time1	t_{IOV1}	10	5	0.01 s	6.3	10	14.7	ms
Input voltage								
Input voltage between VCC and VSS	V_{DS}			Absolute maximum rating	−0.3	–	18	
Operating voltage								
Operating voltage between VCC and VSS [3]	V_{DSOP}				2.0	–	16	V
Current consumption								
Current consumption during normal operation	I_{OPE}	4	2	V1=V2=3.6 V	1.8	7.5	14.2	μA
Current consumption at power down	I_{PDN}	4	2	V1=V2=1.5 V	0	0.0002	0.10	μA
Output voltage								
DO"H"voltage	$V_{DO(H)}$	6	3	Iout=10 μA	V_{CC}−0.17	V_{CC}−0.003	V_{CC}	V
DO"L"voltage	$V_{DO(L)}$	6	3	Iout=10 μA	V_{SS}	V_{SS}+0.003	V_{SS}+0.17	V
CO"H"voltage	$V_{CO(H)}$	7	4	Iout=10 μA	V_{CC}−0.27	V_{CC}−0.019	V_{CC}	V
CO pin internal resistance								
Resistance between VSS and CO	R_{COL}	7	4	V_{CO}−V_{SS}=9.4 V	0.22	0.6	2.20	MΩ
Internal resistance								
Resistance between VCC and VM	R_{vcm}	5	2	Vcc−V_{VM}=0.5 V	79	240	878	kΩ
Resistance between VSS and VM	R_{vsm}	5	2	V_{VM}−V_{SS}=1.1 V	387	597	1491	kΩ
0 V battery charging function								
0 V charge starting voltage	V_{0CHA}	11	6	0 V battery charging Available	0.26	0.75	1.25	V
0 V charge inhibiting voltage 1,2	$V_{0INH1,2}$	12,13	6	0 V battery charging Unavailable	0.20	0.88	1.57	V

(1)   Temperature coefficient 1 for detection voltage should be applied to overcharge detection voltage, overcharge release voltage, overdischarge detection voltage, and overdischarge release voltage.

(2)   Temperature coefficient 2 for detection voltage should be applied to overcurrent detection voltage.

(3)   The DO and CO pin logic are established at the operating voltage.

(4)   Auxiliary overcharge detection voltage is equal to the overcharge detection voltage times 1.11 for the products without overcharge hysteresis, and times 1.25 for other products.

■   Measurement Circuits

(1) Measurement 1 Measurement circuit 1

   Set S1=OFF, V1=V2=3.6 V, and V3=0 V under normal condition. Increase V1 from 3.6 V gradually. The V1 voltage when CO = 'L' is overcharge detection voltage 1 (V_{CU1}). Decrease V1 gradually. The V1 voltage when CO = 'H' is overcharge release voltage 1 (V_{CD1}). Further decrease V1. The V1 voltage when DO = 'L' is overdischarge voltage 1 (V_{DD1}). Increase V1 gradually. The V1 voltage when DO = 'H' is overdischarge release voltage 1 (V_{DU1}). Set S1=ON, and V1=V2=3.6 V and V3=0 V under normal condition. Increase V1 from 3.6 V gradually. The V1 voltage when CO = 'L' is auxiliary overcharge detection voltage 1 (V_{CUaux1}).

(2) Measurement 2 Measurement circuit 1

   Set S1=OFF,V1=V2=3.6 V ,and V3=0 V under normal condition. Increase V2 from 3.6 V gradually. The V2 voltage when CO = 'L' is overcharge detection voltage 2 (V_{CU2}). Decrease V2 gradually. The V2 voltage when CO = 'H' is overcharge release voltage 2 (V_{CD2}). Further decrease V2. The V2 voltage when DO = 'L' is overdischarge voltage 2 (V_{DD2}). Increase V2 gradually. The V2 voltage when DO = 'H' is overdischarge release voltage 2 (V_{DU2}). Set S1=ON,and V1=V2=3.6 V and V3=0 V under normal condition. Increase V2 from 3.6 V gradually. The V2 voltage when CO = 'L' is auxiliary overcharge detection voltage 2 (V_{CUaux2}).

(3) Measurement 3 Measurement circuit 1

   Set S1=OFF,V1=V2=3.6 V , and V3=0 V under normal condition. Increase V3 from 0 V gradually. The V3 voltage when DO = 'L' is overcurrent detection voltage 1 (V_{IOV1}). Set S1=ON,V1=V2=3.6 V,V3=0 under normal condition. Increase V3 from 0 V gradually.(The voltage change rate < 1.0V/ms) (V1+V2−V3) voltage when DO = 'L' is overcurrent detection voltage 2 (V_{IOV2}).

(4) Measurement 4 Measurement circuit 2

   Set S1=ON, V1=V2=3.6 V, and V3=0 V under normal condition and measure current consumption. Current consumption I1 is the normal condition current consumption (I_{OPE}). Set S1=OFF, V1=V2=1.5 V under overdischarge condition and measure current consumption. Current consumption I1 is the power-down current consumption (I_{PDN}).

(5) Measurement 5 Measurement circuit 2

   Set S1=ON, V1=V2=V3=1.5 V, and V3=2.5 V under overdischarge condition. (V1+V2−V3)/I2 is the internal resistance between VCC and VM (R_{vcm}).

   Set S1=ON, V1=V2=3.5 V, and V3=1.1 V under overcurrent condition. V3/I2 is the internal resistance between VSS and VM (R_{vsm}).

(6) Measurement 6 Measurement circuit 3

   Set S1=ON, S2=OFF, V1=V2=3.6 V, and V3=0 V under normal condition. Increase V4 from 0 V gradually. The V4 voltage when I1 = 10 μA is DO'H' voltage ($V_{D0\,(H)}$).

   Set S1=OFF, S2=ON, V1=V2=3.6 V, and V3=0.5 V under overcurrent condition. Increase V5 from 0 V gradually. The V5 voltage when I2 = 10 μA is the DO'L' voltage ($V_{DO\,(L)}$).

(7) Measurement 7 Measurement circuit 4

   Set S1=ON, S2=OFF, V1=V2=3.6 V and V3=0 V under normal condition. Increase V4 from 0 V gradually. The V4 voltage when I1 = 10 μA is the CO'H' voltage ($V_{C0\,(H)}$).

   Set S1=OFF S2=ON, V1=V2=4.7, V3=0 V, and V4=9.4 V under over voltage condition. (V5)/I2 is the CO pin internal resistance (R_{COL}).

(8) Measurement 8 Measurement circuit 5

   Set V1=V2=3.6 V, and V3=0 V under normal condition. Increase V1 from (V_{CU1}−0.2 V) to (V_{CU1}+0.2 V) immediately (within 10 μs). The time after V1 becomes (V_{CU1}+0.2 V) until CO goes 'L' is the overcharge detection delay time 1 (t_{CU1}).

Set V1=V2=3.5 V, and V3=0 V under normal condition. Decrease V1 from (V_{DD1}+0.2 V) to (V_{DD1}−0.2 V) immediately (within 10 μs). The time after V1 becomes (V_{DD1}−0.2 V) until DO goes 'L' is the overdischarge detection delay time 1 (t_{DD1}).

(9) Measurement 9 Measurement circuit 5

Set V1=V2=3.6 V, and V3=0 V under normal condition. Increase V2 from (V_{CU2}−0.2 V) to (V_{CU2}+0.2 V) immediately (within 10 μs). The time after V2 becomes (V_{CU2}+0.2 V) until CO goes 'L' is the overcharge detection delay time 2 (t_{CU2}).

Set V1=V2=3.6 V, and V3=0 V under normal condition. Decrease V2 from (V_{DD2}+0.2 V) to (V_{DD2}−0.2 V) immediately (within 10 μs). The time after V2 becomes (V_{DD2}−0.2 V) until DO goes 'L' is the overdischarge detection delay time 2 (t_{DD2}).

(10) Measurement 10 Measurement circuit 5

Set V1=V2=3.6 V, and V3=0 V under normal condition. Increase V3 from 0 V to 0.5 V immediately (within 10 μs). The time after V3 becomes 0.5 V until DO goes 'L' is the overcurrent detection delay time 1 (t_{IOV1}).

(11) Measurement 11 Measurement circuit 6

Set V1=V2=0 V, and V3=2 V, and decrease V3 gradually. The V3 voltage when CO = 'L' (V_{CC}− 0.3 V or lower) is the 0 V charge starting voltage (V_{0CHA}).

(12) Measurement 12 Measurement circuit 6

Set V1=0 V, V2=3.6 V, and V3=12 V, and increase V1 gradually. The V1 voltage when CO = 'H' (V_{VM}+ 0.3 V or higher) is the 0 V charge inhibiting voltage 1 (V_{0INH1}).

(13) Measurement 13 Measurement circuit 6

Set V1=3.6 V, V2=0 V, and V3=12 V, and increase V2 gradually. The V2 voltage when CO = 'H' (V_{VM}+ 0.3 V or higher) is the 0 V charge inhibiting voltage 2 (V_{0INH2}).
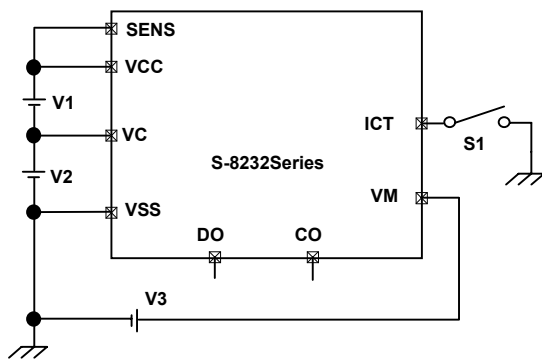
Measurement circuit 1
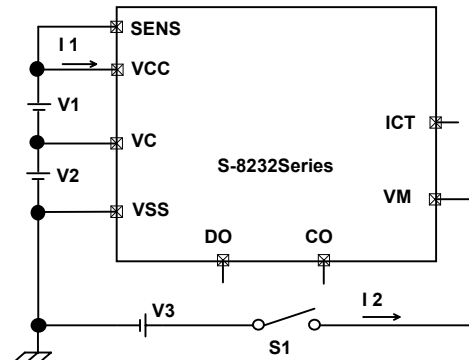
Measurement circuit 2
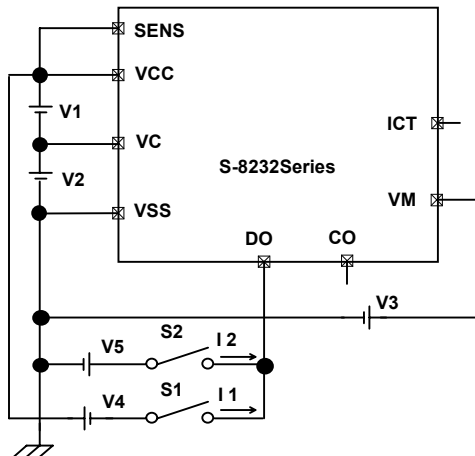
Measurement circuit 3
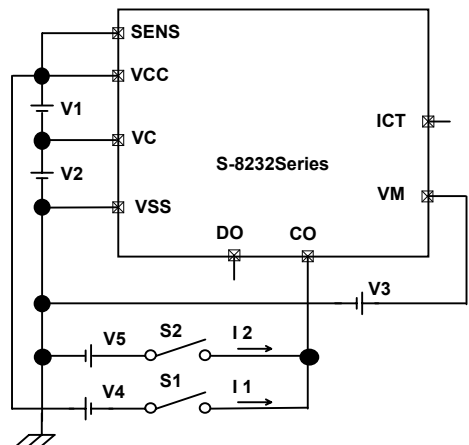
Measurement circuit 4
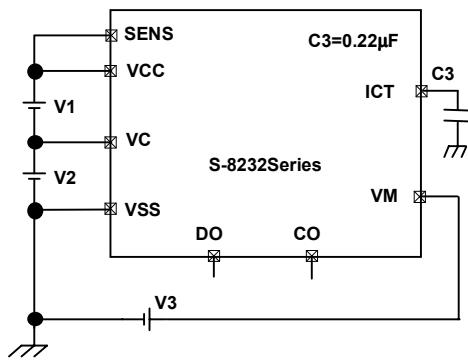
Measurement circuit 5
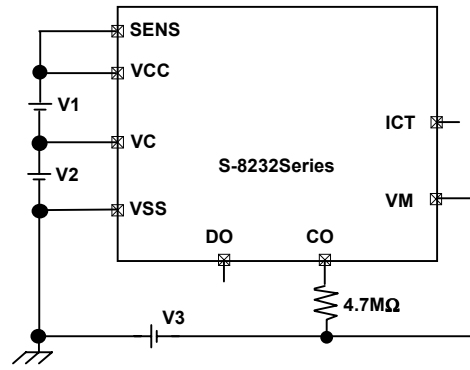
Measurement circuit 6

■ Description of Operation

Normal condition [1], [3]

This IC monitors the voltages of the two serially connected batteries and the discharge current to control charging and discharging. When the voltages of two batteries are in the range from the overdischarge detection voltage ($V_{DD1,2}$) to the overcharge detection voltage ($V_{CU1,2}$), and the current flowing through the batteries becomes equal or lower than a specified value (the VM terminal voltage is equal or lower than overcurrent detection voltage 1), the charging and discharging FETs are turned on. In this condition, charging and discharging can be carried out freely. This condition is called normal condition. In this condition, the VM and VSS terminals are shorted by the R_{vsm} resistor.

Overcurrent condition

When the discharging current becomes equal to or higher than a specified value (the VM terminal voltage is equal to or higher than the overcurrent detection voltage) during discharging under normal condition and it continues for the overcurrent detection delay time (t_{IOV}) or longer, the discharging FET is turned off to stop discharging. This condition is called overcurrent condition. The VM and VSS terminals are shorted by the R_{vsm} resistor at this time. The charging FET is also turned off. When the discharging FET is off and a load is connected, the VM terminal voltage equals the V_{CC} potential.

The overcurrent condition returns to the normal condition when the load is released and the impedance between the EB− and EB+ terminals (see Figure 6 for a connection example) is 200 MΩ or higher. When the load is released, the VM terminal, which is shorted to the VSS terminal with the R_{vsm} resistor, goes back to the V_{SS} potential. The IC detects that the VM terminal potential returns to overcurrent detection voltage 1 (V_{IOV1}) or lower and returns to the normal condition.

Overcharge condition

Following two cases are detected as overcharge conditions:
1) If one of the battery voltages becomes higher than the overcharge detection voltage ($V_{CU1,2}$) during charging under normal condition and it continues for the overcharge detection delay time ($t_{CU1,2}$) or longer, the charging FET turns off to stop charging.
2) If one of the battery voltages becomes higher than the auxiliary overcharge detection voltage ($V_{CUaux1,2}$) the charging FET turns off immediately to stop charging.

The VM and VSS terminals are shorted by the R_{vsm} resistor under the overcharge condition.

The auxiliary overcharge detection voltages ($V_{CUaux1,2}$) are correlated with the overcharge detection voltages ($V_{CU1,2}$) and are defined by following equations:

$$V_{CUaux1,2} \text{ [V]} = 1.25 \times V_{CU1,2} \text{ [V]}$$

or for no overcharge hysteresis type ($V_{CU1,2} = V_{CD1,2}$)

$$V_{CUaux1,2} \text{ [V]} = 1.11 \times V_{CU1,2} \text{ [V]}$$

The overcharge condition is released in two cases:

1) The battery voltage which exceeded the overcharge detection voltage ($V_{CU1,2}$) falls below the overcharge release voltage ($V_{CD1,2}$), the charging FET turns on and the normal condition returns.
2) If the battery voltage which exceeded the overcharge detection voltage ($V_{CU1,2}$) is equal or higher than the overcharge release voltage ($V_{CD1,2}$), but the charger is removed, a load is placed, and discharging starts, the charging FET turns on and the normal condition returns.

The release mechanism is as follows: the discharge current flows through an internal parasitic diode of the charging FET immediately after a load is installed and discharging starts, and the VM terminal voltage decreases by about 0.6 V from the VSS terminal voltage momentarily. The IC detects this voltage (overcurrent detection voltage 1 or higher), releases the overcharge condition and returns to the normal condition.

Overdischarge condition

If any one of the battery voltages falls below the overdischarge detection voltage ($V_{DD1,2}$) during discharging under normal condition and it continues for the overdischarge detection delay time ($t_{DD1,2}$) or longer, the discharging FET turns off and discharging stops. This condition is called the overdischarge condition. When the discharging FET turns off, the VM terminal voltage becomes equal to the V_{CC} voltage and the IC's current consumption falls below the power-down current consumption (I_{PDN}). This condition is called the power-down condition. The VM and VCC terminals are shorted by the R_{vcm} resistor under the overdischarge and power-down conditions.

The power-down condition is canceled when the charger is connected and the voltage between VM and VCC is overcurrent detection voltage 2 or higher. When all the battery voltages becomes equal to or higher than the overdischarge release voltage ($V_{DU1,2}$) in this condition, the overdischarge condition changes to the normal condition.

Delay circuits

The overcharge detection delay time ($t_{CU1,2}$), the overdischarge detection delay time ($t_{DD1,2}$), and the overcurrent detection delay time 1 (t_{I0V1}) change with an external capacitor (C3). Since one capacitor determine each delay time, delay times are correlated by the following ratio:

Overcharge delay time : Overdischarge delay time: Overcurrent delay time = 100 : 10 : 1

The delay times are calculated by the following equations: (Ta=−40 to +85°C)

Overcharge detection delay time   Min.,   Typ.,   Max.
       t_{CU}[s] =Delay factor (2.500,   4.545,   9.364   )×C3 [μF]
Overdischarge detection delay time
       t_{DD}[s] =Delay factor (0.3045,   0.4545,   0.6409)×C3 [μF]
Overcurrent detection delay time
       t_{IOV1}[s]=Delay factor (0.02864, 0.04545, 0.06682)×C3 [μF]

Note: The delay time for overcurrent detection 2 is fixed by an internal circuit. The delay time cannot be changed via an external capacitor.

0 V battery charging function [2]

This function is used to recharge both of two serially-connected batteries after they self-discharge to 0 V. When the 0 V charging start voltage (V_{0CHA}) or higher is applied to between VM and VCC by connecting the charger, the charging FET gate is fixed to V_{CC} potential.

When the voltage between the gate sources of the charging FET becomes equal to or higher than the turn-on voltage by the charger voltage, the charging FET turns on to start charging. At this time, the discharging FET turns off and the charging current flows through the internal parasitic diode in the discharging FET. If all the battery voltages become equal to or higher than the overdischarge release voltage ($V_{DU1,2}$), the normal condition returns.

0 V battery charge inhibiting function [(2)]

This function is used for inhibiting charging when either of the connected batteries goes 0 V due to its self-discharge. When the voltage of either of the connected batteries goes below 0 V charge inhibit voltage 1 and 2 ($V_{OINH1, 2}$), the charging FET gate is fixed to "EB −" to inhibit charging. Charging is possible only when the voltage of both connected batteries goes 0 V charge inhibit voltage 1 and 2 ($V_{OINH1, 2}$) or more.

Note that charging may be possible when the total voltage of both connected batteries is less than the minimum value ($V_{DSOPmin}$) of the operating voltage between VCC-VSS even if the voltage of either of the connected batteries is 0 V charge inhibit voltage 1 and 2 ($V_{0INH1, 2}$) or less. Charging is prohibited when the total voltage of both connected batteries reaches the minimum value ($V_{DSOPmin}$) of the operating voltage between VCC-VSS.

When using this optional function, a resistor of 4.7 MΩ is needed between the gate and the source of the charging control FET (refer to Figure 6).

(1)

When initially connecting batteries, the IC may fail to enter the normal condition (discharging ready state). If so, once set the VM pin to VSS voltage (short pins VM and VSS or connect a charger).

(2)

Some lithium ion batteries are not recommended to be recharged after having been completely discharged. Please contact the battery manufacturer when you decide to select a 0 V battery charging function.

(3)

The products indicated with 4) in the Selection Guide (model name/item) are set to "overcharge detection/release hysteresis," "no final overcharge function," and "0 V battery charge inhibiting function." The following phenomena may be found, but there is no problem for practical use.
The product is an overcurrent condition due to overload connection when the battery voltage is overcharge release voltage ($V_{CD1, 2}$) or more and overcharge detection voltage ($V_{CU1, 2}$) or less. Usually, the IC returns to its normal condition when overload is removed under this condition. However, the charging FET may be turned OFF when overload is removed under this condition, leading to an overcharge condition. If so, attach load to start discharge. The charging FET is turned ON to return to the normal condition. Refer to "Overcharge condition" of description Section.

■ Operation Timing Charts

1. Overcharge detection

Note: ①Normal mode, ②Over charge mode,③Over discharge mode, ④over current mode
The charger is assumed to charge with a constant current.
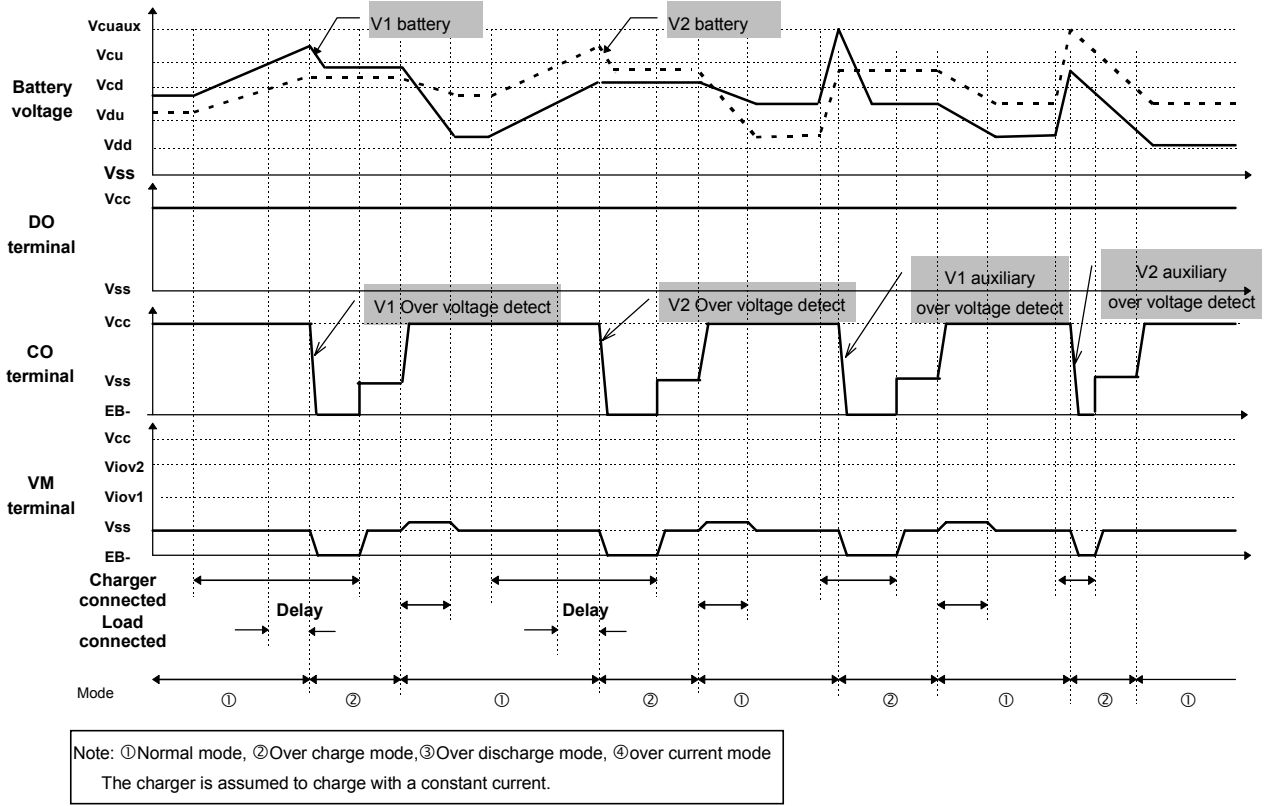
Figure 3

2. Overdischarge detection

Note: ①Normal mode, ②Over charge mode,③Over discharge mode, ④over current mode
The charger is assumed to charge with a constant current.
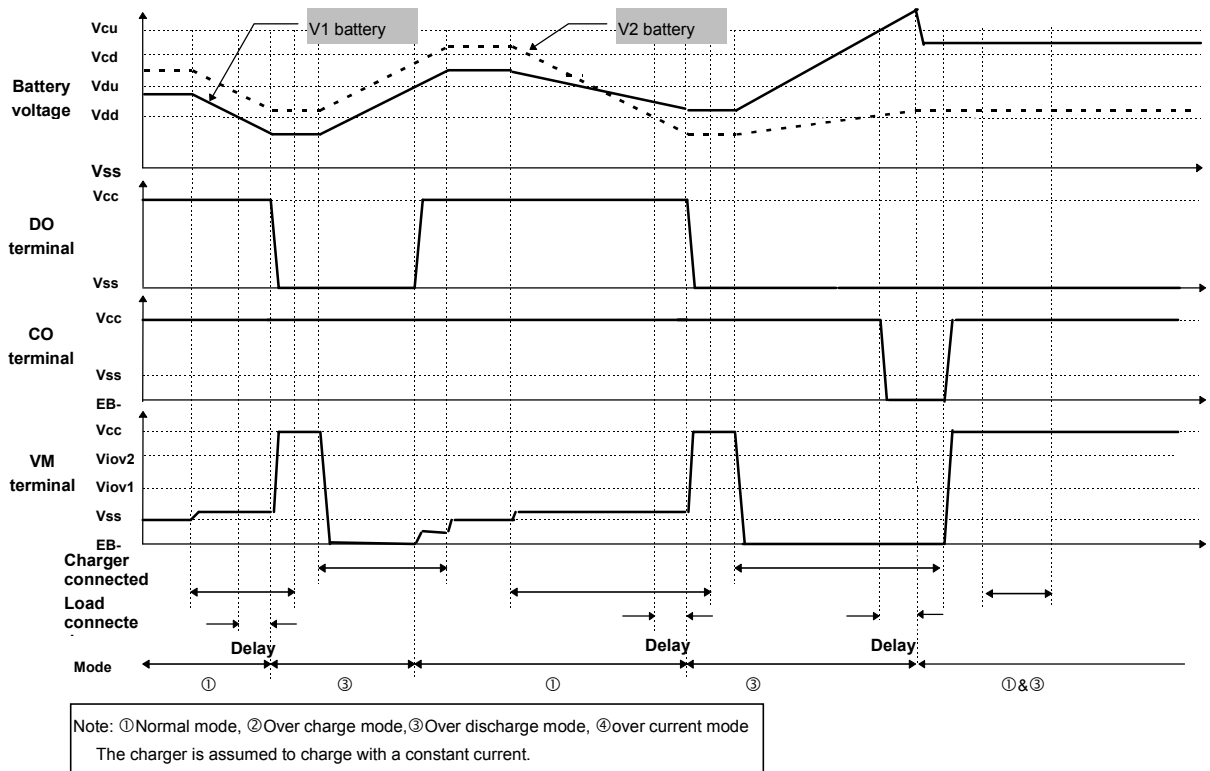
Figure 4

3. Overcurrent detection

Note: ①Normal mode, ②Over charge mode,③Over discharge mode, ④over current mode
The charger is assumed to charge with a constant current.
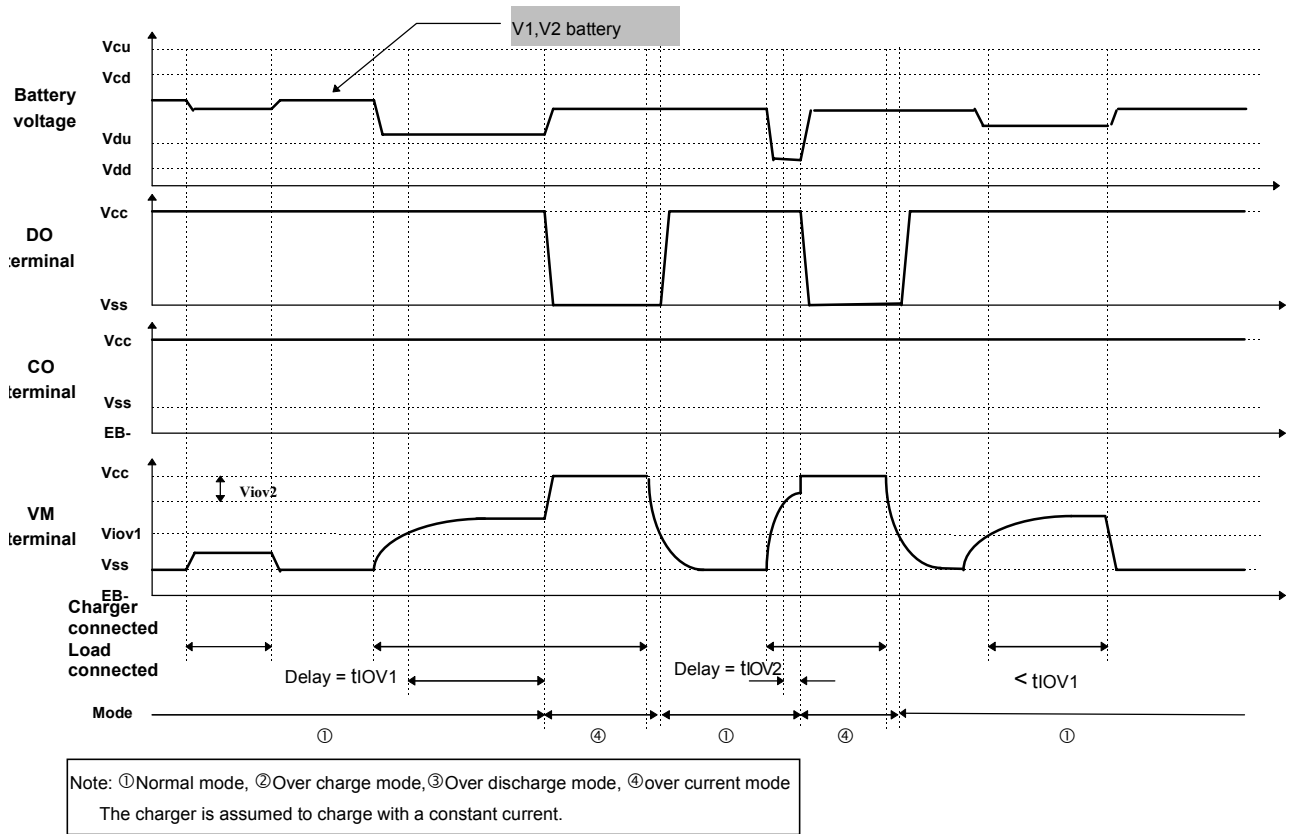
Figure 5

■ Battery Protection IC Connection Example
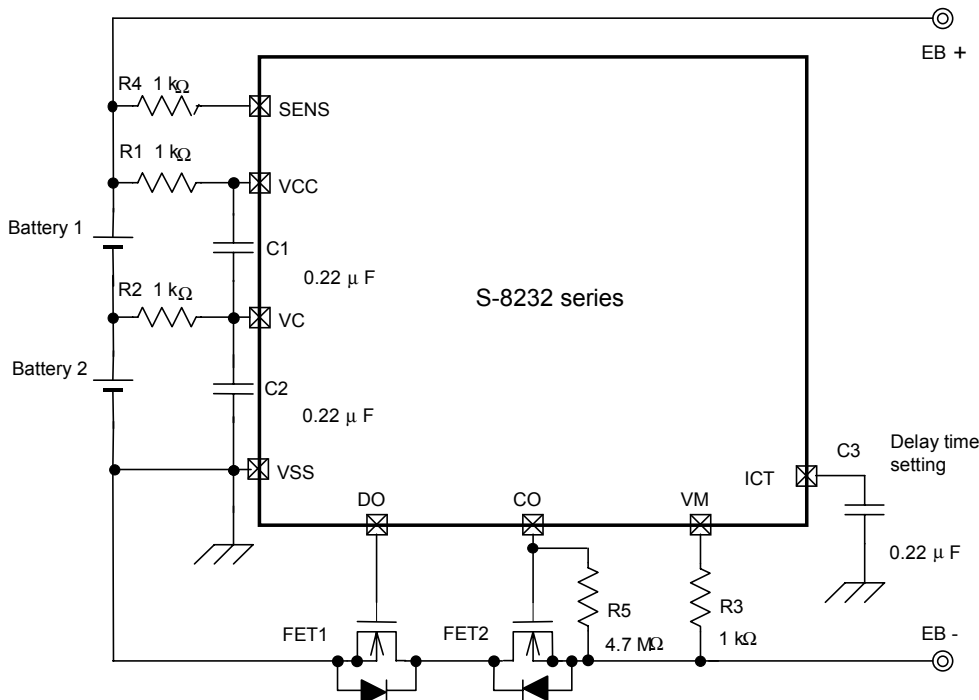
Figure 6

Table 8 Constant

Symbol	Parts	Purpose	Recommended	min.	max.	Remarks
FET1	Nch MOSFET	Charge control	-----	-----	-----	-----
FET2	Nch MOSFET	Discharge control	-----	-----	-----	-----
R1	Chip resistor	ESD protection	1 kΩ	300 Ω	1 kΩ	
C1	Chip capacitor	Filter	0.22 μF	0 μF	1 μF	
R2	Chip resistor	ESD protection	1 kΩ	300 Ω	1 kΩ	
C2	Chip capacitor	Filter	0.22 μF	0 μF	1 μF	
R4	Chip resistor	ESD protection	1 kΩ	=R1 min.	=R1 max.	1) Same value as R1 and R2
C3	Chip capacitor	Delay time setting	0.22 μF	0 μF	1 μF	2) Attention should be paid to leak current of C3.
R3	Chip resistor	Protection for charger reverse connection	1 kΩ	300 Ω	5 kΩ	3) Discharge can't be stopped at less than 300 Ω when a charger is reverse-connected.
R5	Chip resistor	0 V battery charging inhibition	(4.7 MΩ)	(1 MΩ)	(10MΩ)	4) R5 should be added when the product has 0 V battery charge inhibition. Lower resistance increases current consumption.

1） R4 =R1 is required. Overcharge detection voltage increases by R4. For example 10 kΩ (R4) increases overcharge detection voltage by 20 mV.

2） The overcharge detection delay time (t_{CU}), the overdischarge detection delay time (t_{CD}), and the over current detection delay time (t_{IOV}) change with the external capacitor C3. See the electrical characteristics.

3） When the resistor R3 is set less than 300 Ω and a charger is reverse-connected, current which exceeds the power dissipation of the package will flow and the IC may break. But excessive R3 causes increase of overcurrent detection voltage 1 (V_{IOV1}). V_{IOV1} changes to $V_{IOV1}=(R3+R_{vsm})/R_{vsm}\times V_{IOV1}$. For example 50 kΩ resistor (R3) increases overcurrent detection voltage 1 (V_{IOV1}) from 0.100 V to 0.113 V.

4） A 4.7 MΩ resistor is needed for R5 to inhibit 0 V battery charging. Current consumption increases when the R5 resistance increases. R5 should be connected when the product has 0 V battery charging inhibition.

Note:
The above connection diagram and constants do not guarantee proper operations. Evaluate your actual application and set constants properly.

■   Precautions

(1) After the overcurrent detection delay, if the battery voltages is equals the overdischarge detection voltage
($V_{DD1,2}$) or lower, the overdischarge detection delay time becomes shorter than 10ms (min.).
It occurs because capacitor C3 sets all of delay times. (Refer fig.7)

[Cause]

It occurs because capacitor C3 sets all of delay
times. When overcurrent detection is released
until t_{IOV1} , the capacitor C3 is charged by S-
8232. If all battery voltage is lower than $V_{DD1,2}$ at
that time, charging goes on. So delay time is
shorter then typical.

[Conclusion]

This phenomenon occurs when all battery
voltage is nearly equal to the overdischarge
voltage ($V_{DD1,2}$) after overcurrent detected. It
means that the battery capacity is small and
those must be charged in the future. Even if the
state changes to overdischarge condition, the
battery package capacity is same as typical.

Figure 7
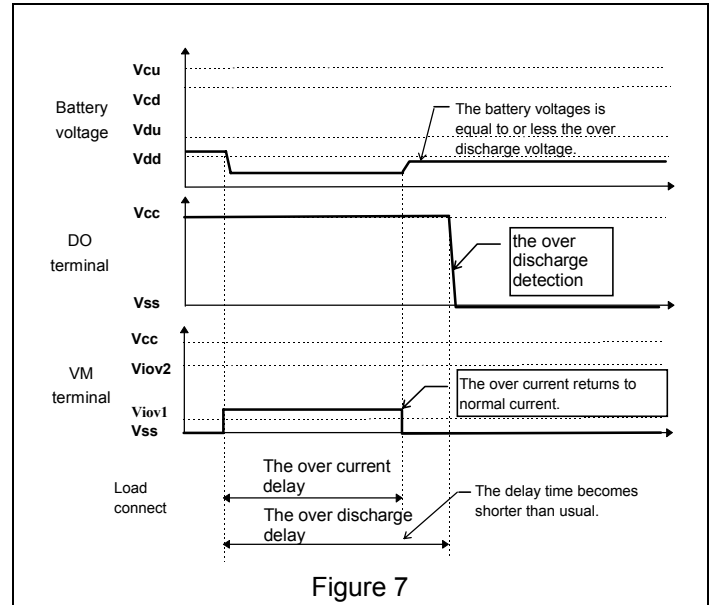
(2) When one of the battery voltages is overdischarge detection voltage($V_{DD1,2}$) or lower and the other one
becomes higher than the overcharge detection voltage($V_{CU1,2}$), the IC detects the overcharge without the
overcharge detection delay time(t_{CU}). (Refer fig.8)

[Cause]

It is same as the overdischarge detection under
the overcurrent condition. It occurs because
capacitor C3 sets all of delay times.

[Conclusion]

This phenomenon occurs when one battery
voltage is lower than overdischarge voltage
($V_{DD1,2}$) and batteries are charged by charger.
Under this situation voltage difference between
two batteries is unusual. Without delay time is
better than long delay time for battery pack
safety.(Refer fig.8)

Figure 8
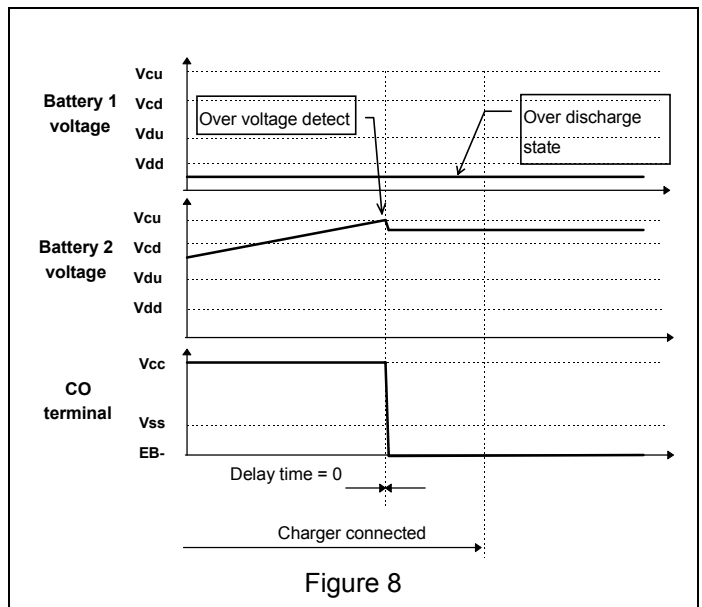
(3) After the overcurrent detection, the load was connected for a long time, even if one of the battery voltage
became lower than overdischarge detection voltage ($V_{DD1,2}$), the IC can't detects the overdischarge as long as
the load is connected. Therefor the IC's current consumption at the one of the battery voltage is lower than the
overdischarge detection voltage is same as normal condition current consumption (I_{OPE}) . (Refer fig.9)

[Cause]

The reason is as follows. If the overcurrent detection and overdischarge detection occur at same time, the overcurrent detection takes precedence the overdischarge detection.
As long as the IC detects overcurrent, the IC can't detect overdischarge.

[Conclusion]

If the load is taken off at least one time, the overcurrent is released and the overdischarge detection works.
Unless keeping the IC(S-8232) with load for a long time, the reduction of battery voltage will be neglected, because of the IC's(S-8232) current consumption(typ. 7.5 μA) is small.
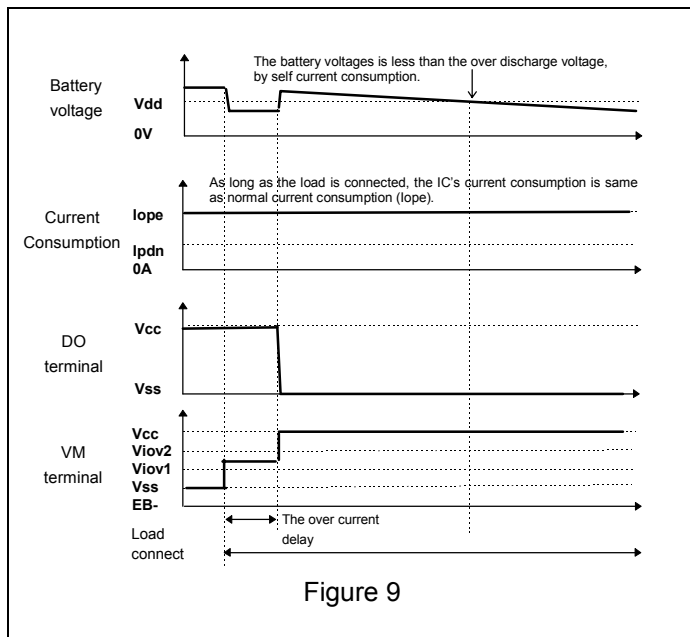
Figure 9

(4) Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.

■ Characteristics(typical characteristics)

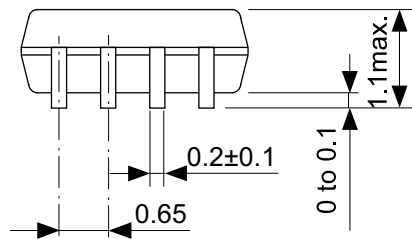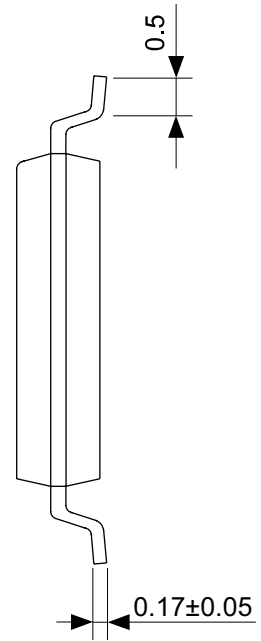### 1. Detection voltage temperature characteristics
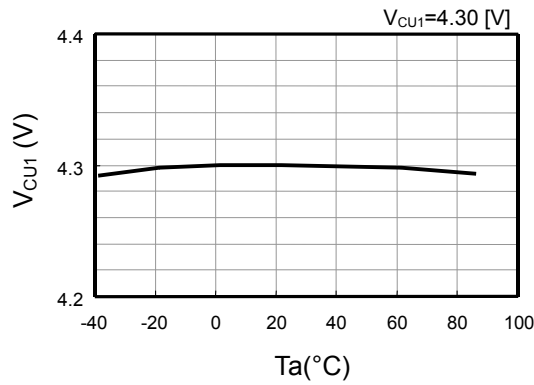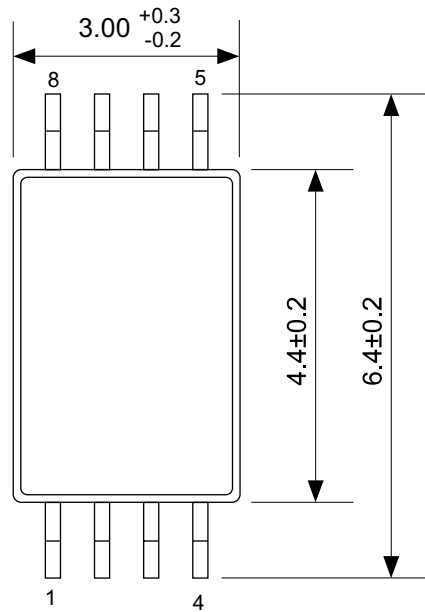
Overcharge detection voltage1 vs. temperature

V_{CU1}=4.30 [V]

Overcharge detection voltage2 vs. temperature

V_{CU2}=4.30 [V]

Overcharge release voltage1 vs. temperature

V_{CD1}=4.00 [V]
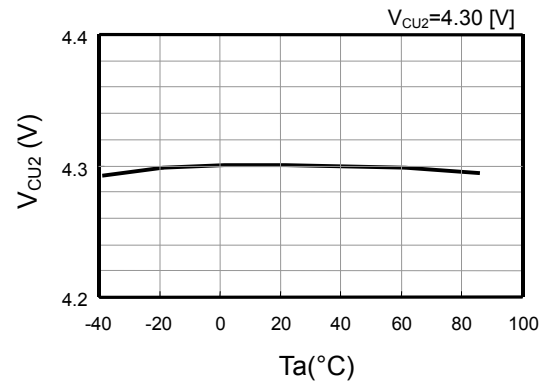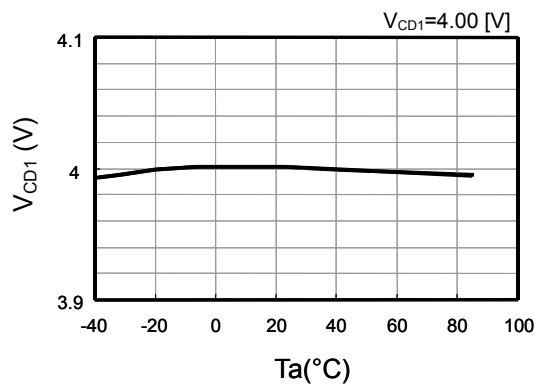
Overcharge release voltage2 vs. temperature
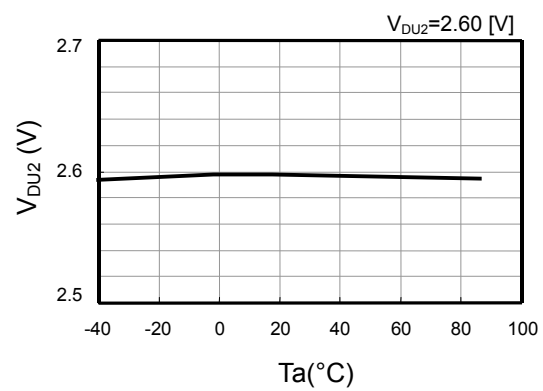
V_{CD2}=4.00 [V]

Auxiliary overcharge detection voltage1 vs. temperature

V_{CUaux1}=5.375[V]

Auxiliary overcharge detection voltage2 vs. temperature

V_{CUaux2}=5.375[V]

Overdischarge detection voltage1 vs. temperature

V_{DD1}=2.00 [V]

Overdischarge detection voltage2 vs. temperature

V_{DD2}=2.00 [V]

Overdischarge release voltage1 vs. temperature

V_{DU1}=2.60 [V]

Overdischarge release voltage1 vs. temperature

V_{DU2}=2.60 [V]

Overcurrent1 detection voltage vs. temperature

V_{IOV1}=0.1 [V]

Overcurrent1 detection voltage vs. temperature
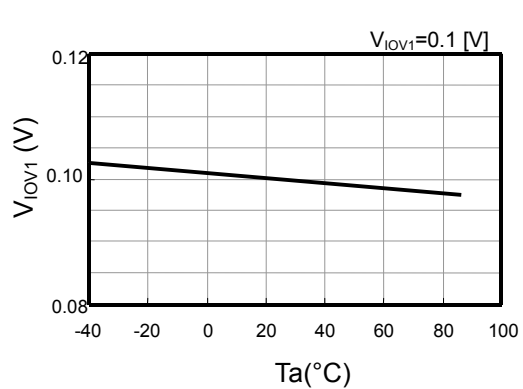
V_{IOV2}=1.20 [V] (V_{CC} reference)
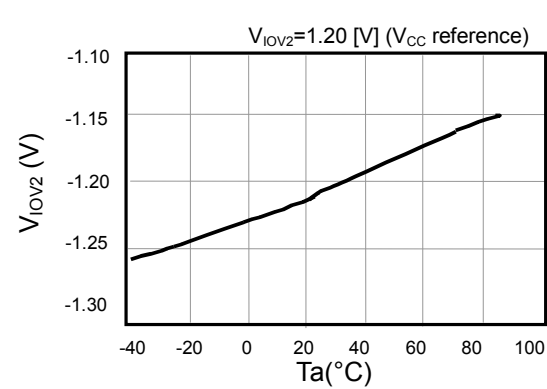
2.Current consumption temperature characteristics

Current consumption vs. temperature in normal mode

V_{CC}=7.2 [V]
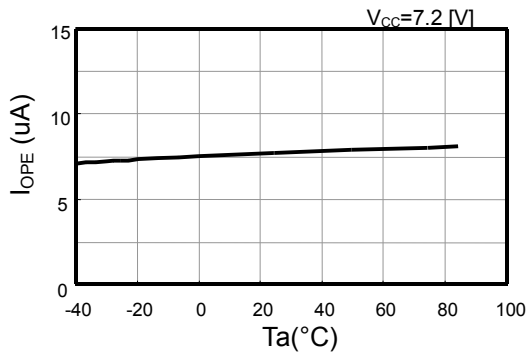
Current consumption vs. temperature in power-down mode

V_{CC}=3.0 [V]
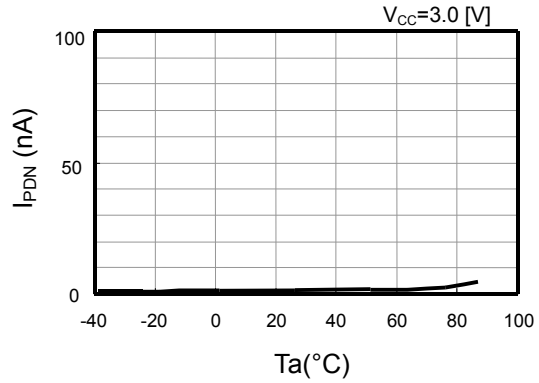
3. Delay time temperature characteristics

Overcharge detection1 time vs. temperature

C3=0.22 [uF]

Overcharge detection1 time vs. temperature

C3=0.22 [uF]
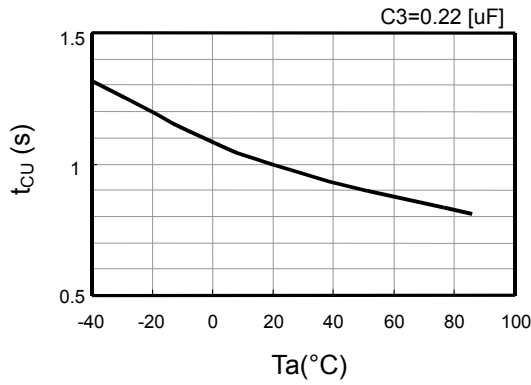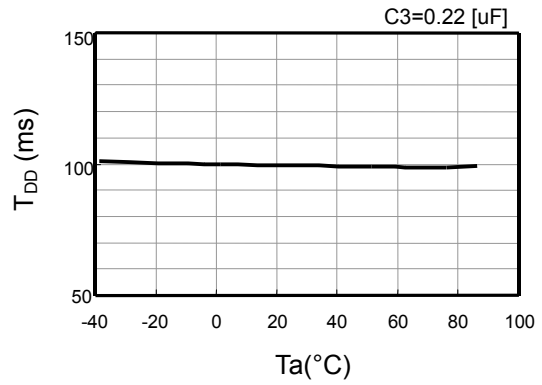
Overcurrent1 detection time vs. temperature

C3=0.22 [uF]

3.00 +0.3 -0.2

8   5

4.4±0.2

6.4±0.2

1   4

0.5

0.17±0.05

1.1max.

0 to 0.1

0.2±0.1

0.65
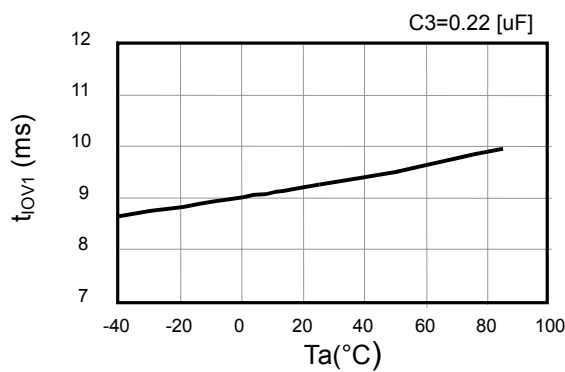
No. FT008-A-P-SD-1.1

TITLE	TSSOP8-A-PKG Dimensions
No.	FT008-A-P-SD-1.1
SCALE	
UNIT	mm

Seiko Instruments Inc.

4.0±0.1(50 pitches:200.0±0.3)

2.0±0.05

1.55±0.05

1.75±0.1

0.3±0.05

5.5±0.05

12.0±0.3

8.0±0.1

1.55 +0.1 -0

7° max.

(3.6)

3.3 +0.4 -0.2

1.4±0.1

(6.9)

7° max.

4.0

1.4±0.1

1.7±0.1

6.6 +0.4 -0.2

1

8

4

5
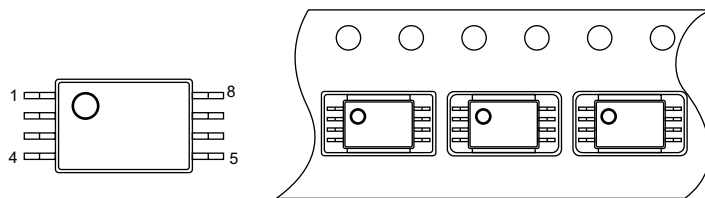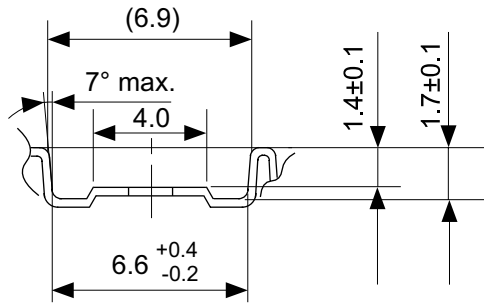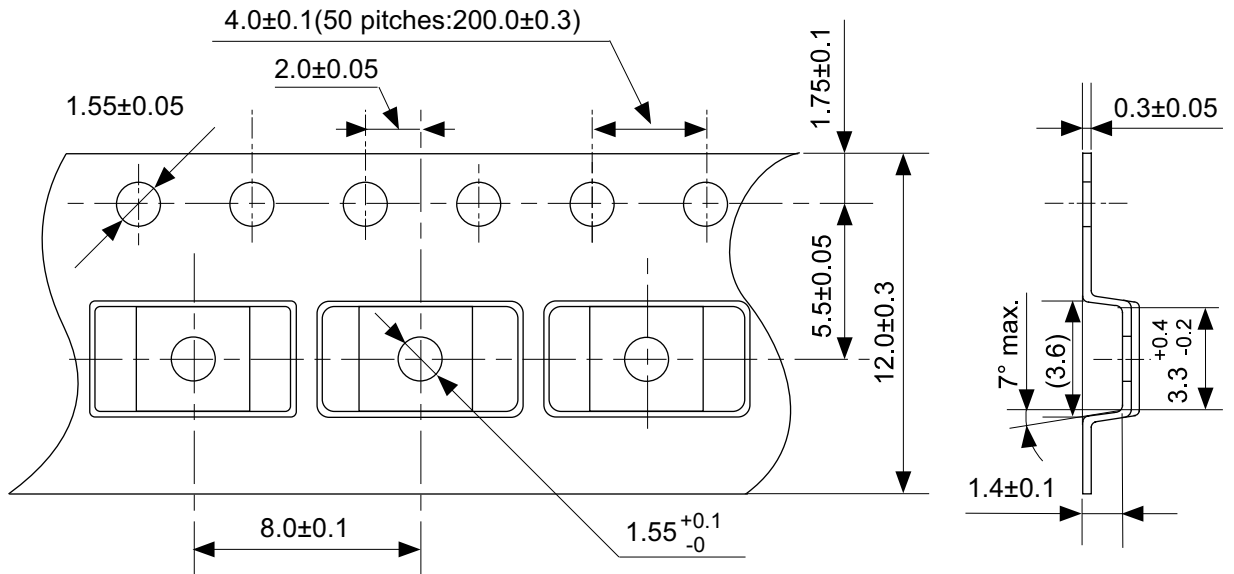
No. FT008-A-C-SD-3.1

Feed direction

TITLE	TSSOP8-A-Carrier Tape
No.	FT008-A-C-SD-3.1
SCALE	
UNIT	mm

Seiko Instruments Inc.

R135

ø100 +2 -0

ø330±2

13.4±1.0

17.5±1.0

Enlarged drawing in the central part

ø21±0.8

2±0.5

ø13±0.5
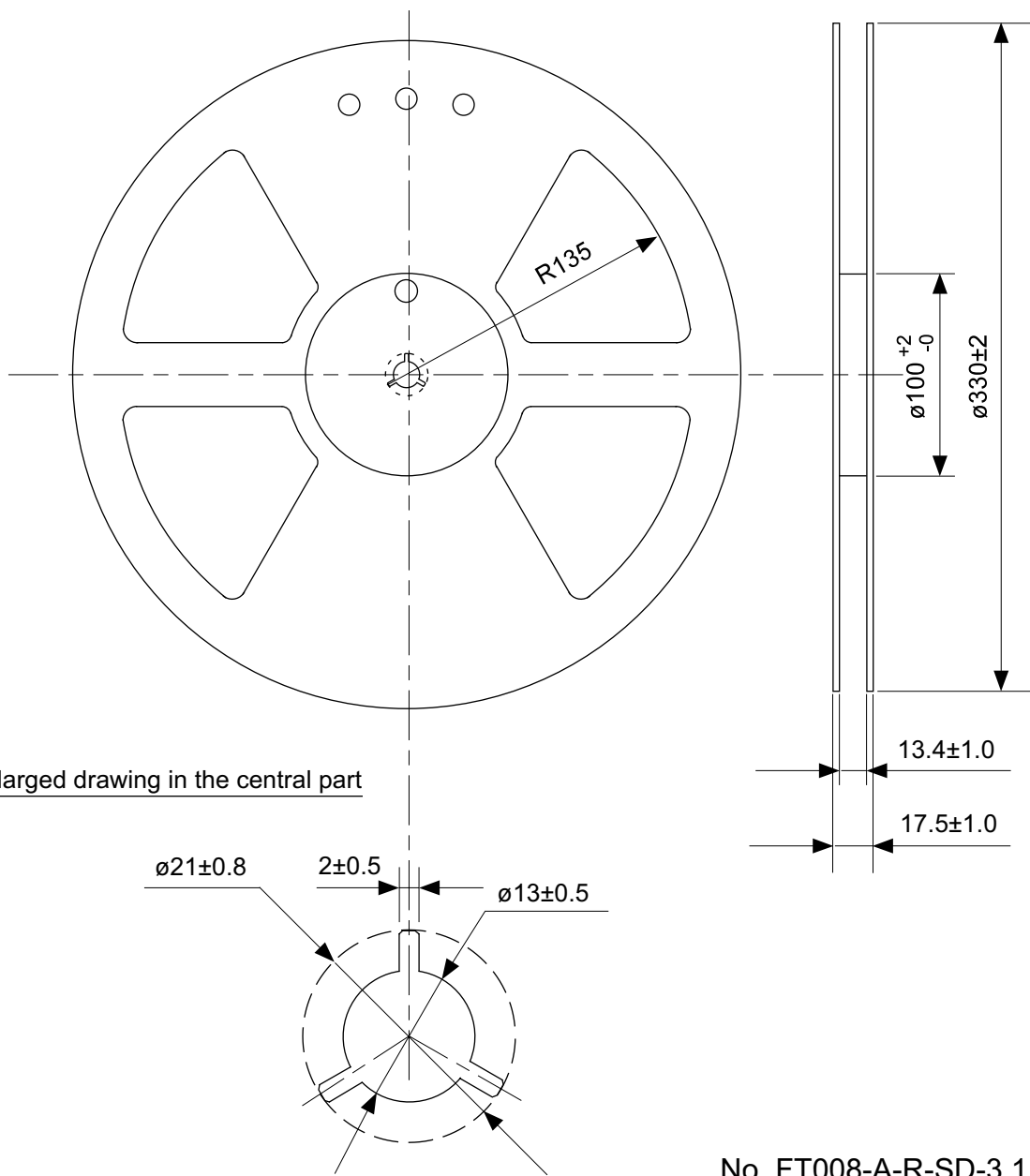
No. FT008-A-R-SD-3.1

TITLE	TSSOP8-A-Reel		
No.	FT008-A-R-SD-3.1		
SCALE		QTY.	3,000
UNIT	mm		
Seiko Instruments Inc.			